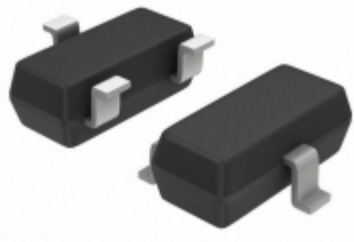









	<h2 style="color: red;">MUN2214T1G</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">MUN2214T1G</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	TRANS PREBIAS NPN 230MW SC59
<b>Datenblätter:</b>	 <a href="#">MUN2214T1G.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 35375 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">MUN2214T1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	TRANS PREBIAS NPN 230MW SC59
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-Bipolar</a>
Teilstatus	35375 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	230mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SC-59
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

MUN2214T1G ist neu im Original, Suche MUN2214T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie MUN2214T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage MUN2214T1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>MUN2215LT1G</b> ON MUN2215LT1G ON</p>	 <p><b>MUN2215T1</b> MOT MUN2215T1 MOT</p>	 <p><b>MUN2214T3G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59</p>	 <p><b>MUN2213T1</b> ON MUN2213T1 ON</p>
 <p><b>MUN2213T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59</p>	 <p><b>MUN2215T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59</p>	 <p><b>MUN2213JT1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59</p>	 <p><b>MUN2215LT1</b> ON MUN2215LT1 ON</p>

### heiße Teile

Mehr

<ul style="list-style-type: none"> <li>⊗ 1MBI1000UG-330</li> <li>⊣ MUN2112T1</li> <li>⊗ MUN2114T1</li> <li>D MUN2132T1</li> <li>⇒ MUN2211T1G/3G</li> <li>⇒ MUN2213JT1</li> <li>⊗ MUN2215LT1G</li> <li>⊣ MUN2232T1G</li> <li>⊗ MUN2237T1</li> <li>⇒ MUN5213T1</li> </ul>	<ul style="list-style-type: none"> <li>⇒ MUN2111LT1</li> <li>⊗ MUN2112T1G</li> <li>⊣ MUN2114T1G</li> <li>⊗ MUN2133T1</li> <li>⇒ MUN2211T3G</li> <li>⇒ MUN2213JT1G</li> <li>D MUN2215T1</li> <li>⊗ MUN2233LT1G</li> <li>⊣ MUN2237T1G</li> <li>⊗ MUN5215T1G</li> </ul>	<ul style="list-style-type: none"> <li>⇒ MUN2111T1</li> <li>D MUN2113T1</li> <li>⊗ MUN2115T1</li> <li>⊣ MUN2211T1</li> <li>⊗ MUN2212LT1</li> <li>D MUN2213T1</li> <li>⇒ MUN2215T1G</li> <li>⇒ MUN2233RT1</li> <li>⊗ MUN5113T1G</li> <li>⊣ MUN5312DW1T2</li> </ul>	<ul style="list-style-type: none"> <li>D MUN2111T1G</li> <li>⇒ MUN2113T1G</li> <li>⇒ MUN2116T1</li> <li>⊗ MUN2211T1B</li> <li>⊣ MUN2212T1</li> <li>⊗ MUN2213T1G</li> <li>⇒ MUN2216T1</li> <li>⇒ MUN2233T1G</li> <li>D MUN5114T1G</li> <li>⊗ MUN5313DW1T1G</li> </ul>	<ul style="list-style-type: none"> <li>⇒ MUN2112LT1G</li> <li>⇒ MUN2113XLT1</li> <li>⇒ MUN2116T1G</li> <li>⇒ MUN2211T1G</li> <li>⇒ MUN2212T1G</li> <li>⊣ MUN2215LT1</li> <li>⇒ MUN2216T1G</li> <li>⇒ MUN2234T1G</li> <li>⇒ MUN5115DW1T1G</li> <li>⇒ STPS5H100B</li> </ul>
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Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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